Panasonic

2SB0949 (2SB949), 2SB0949A (2SB949A)

Silicon PNP epitaxial planar type darlington

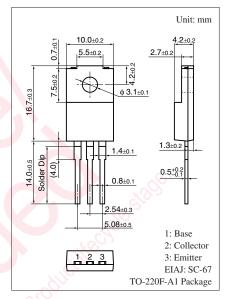
For power amplification and switching Complementary to 2SD1275 and 2SD1275A

■ Features

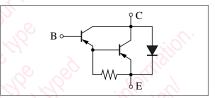
- High forward current transfer ratio h_{FE}
- High-speed switching
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | Symbol | Rating | Unit | |
|----------------------------|---------------------|------------------|------|---|
| Collector-base voltage | 2SB0949 | V _{CBO} | -60 | V |
| (Emitter open) | 2SB0949A | | -80 | |
| Collector-emitter voltage | 2SB0949 | V _{CEO} | -60 | V |
| (Base open) | 2SB0949A | | -80 | |
| Emitter-base voltage (Coll | V _{EBO} | -5 | V | |
| Collector current | I_{C} | -2 | A | |
| Peak collector current | I_{CP} | -4 | A | |
| Collector power | $T_C = 25^{\circ}C$ | P_{C} | 35 | W |
| dissipation | | | 2 | |
| Junction temperature | T _j | 150 | °C | |
| Storage temperature | T_{stg} | -55 to +150 | °C | |



Internal Connection



■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

| Parameter | | Symbol | Conditions | Min | Тур | Max | Unit |
|--|----------|----------------------|---|-------|------|--------|------|
| Collector-emitter voltage | 2SB0949 | V _{CEO} | $I_C = -30 \text{ mA}, I_B = 0$ | -60 | ٠ C | Ö | V |
| (Base open) | 2SB0949A | | | -80 | -0/1 | | |
| Base-emitter voltage | | V_{BE} | $V_{CE} = -4 \text{ V}, I_{C} = -2 \text{ A}$ | 200 | 55 | -2.8 | V |
| Collector-base cutoff | 2SB0949 | I_{CBO} | $V_{CB} = -60 \text{ V}, I_E = 0$ | 09) | | -1 | mA |
| current (Emitter open) | 2SB0949A | | $V_{CB} = -80 \text{ V}, I_E = 0$ | | | -1 | |
| Collector-emitter cutoff | 2SB0949 | I_{CEO} | $V_{CE} = -30 \text{ V}, I_B = 0$ | | | -2 | mA |
| current (Base open) | 2SB0949A | | $V_{CE} = -40 \text{ V}, I_{B} = 0$ | | | -2 | |
| Emitter-base cutoff current (Collector open) | | I_{EBO} | $V_{EB} = -5 \text{ V}, I_C = 0$ | | | -2 | mA |
| Forward current transfer ratio | | h _{FE1} | $V_{CE} = -4 \text{ V}, I_{C} = -1 \text{ A}$ | 1 000 | | | _ |
| | | h _{FE2} * | $V_{CE} = -4 \text{ V}, I_{C} = -2 \text{ A}$ | 1 000 | | 10 000 | |
| Collector-emitter saturation voltage | | V _{CE(sat)} | $I_C = -2 \text{ A}, I_B = -8 \text{ mA}$ | | | -2.5 | V |
| Transition frequency | | f_T | $V_{CE} = -10 \text{ V}, I_{C} = -0.5 \text{ A}, f = 1 \text{ MHz}$ | | 20 | | MHz |
| Turn-on time | | t _{on} | $I_C = -2 \text{ A}, I_{B1} = -8 \text{ mA}, I_{B2} = 8 \text{ mA}$ | | 0.4 | | μs |
| Storage time | | t _{stg} | $V_{CC} = -50 \text{ V}$ | | 1.5 | | μs |
| Fall time | | $t_{\rm f}$ | | | 0.5 | | μs |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

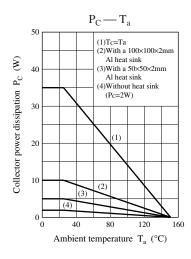
2. *: Rank classification

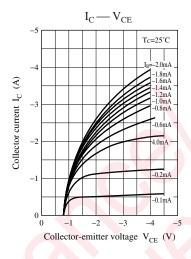
| Rank | R | Q | Р | |
|------------------|--------------|--------------|---------------|--|
| h _{FE2} | 1000 to 2500 | 2000 to 5000 | 4000 to 10000 | |

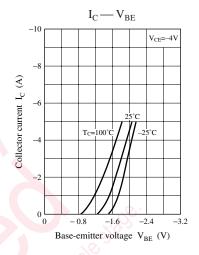
Note) The part numbers in the parenthesis show conventional part number.

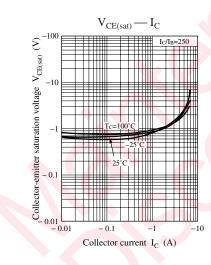
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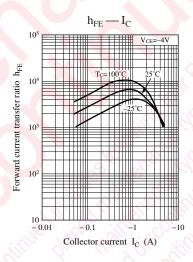
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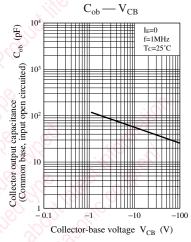


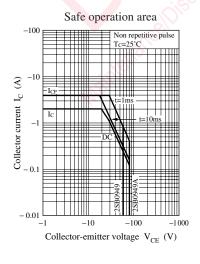


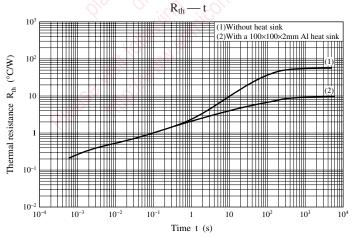












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